Hex Schmitt-Trigger Inverter with LSTTL Compatible Inputs

High–Performance Silicon–Gate CMOS

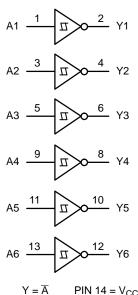
The MC74HCT14A may be used as a level converter for interfacing TTL or NMOS outputs to high–speed CMOS inputs.

The HCT14A is useful to "square up" slow input rise and fall times. Due to the hysteresis voltage of the Schmitt trigger, the HCT14A finds applications in noisy environments.

Features

- Output Drive Capability: 10 LSTTL Loads
- TTL/NMOS-Compatible Input Levels
- Outputs Directly Interface to CMOS, NMOS, and TTL
- Operating Voltage Range: 4.5 to 5.5 V
- Low Input Current: 1.0 μA
- In Compliance With the JEDEC Standard No. 7.0 A Requirements
- Chip Complexity: 72 FETs or 18 Equivalent Gates
- NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable
- These Devices are Pb-Free, Halogen Free and are RoHS Compliant

LOGIC DIAGRAM



PIN 7 = GND



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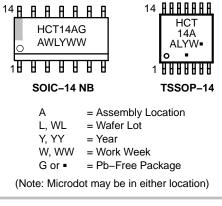
D SUFFIX CASE 751A

TSSOP-14 DT SUFFIX CASE 948G

PIN ASSIGNMENT

| A1 [| 1● | | l v _{cc} |
|-------|----|----|-------------------|
| Y1 [| 2 | 13 |] A6 |
| A2 [| | 12 | D Y6 |
| Y2 [| 4 | 11 |] A5 |
| A3 [| 5 | 10 |] Y5 |
| Y3 [| 6 | 9 |] A4 |
| GND [| 7 | 8 |] Y4 |
| | | | |

MARKING DIAGRAMS



FUNCTION TABLE

| Input A | Output Y |
|------------|-------------|
| L | Н |
| н | L |

ORDERING INFORMATION

See detailed ordering and shipping information in the package dimensions section on page 4 of this data sheet.

MAXIMUM RATINGS

| Symbol | F | Parameter | Value | Unit |
|----------------------|--|--|-------------------------------|------|
| V _{CC} | DC Supply Voltage | (Referenced to GND) | -0.5 to +7.0 | V |
| VI | DC Input Voltage | (Referenced to GND) | –0.5 to V _{CC} + 0.5 | V |
| Vo | DC Output Voltage | (Referenced to GND) | –0.5 to V _{CC} + 0.5 | V |
| I _{IK} | DC Input Diode Current | | ±20 | mA |
| I _{OK} | DC Output Diode Current | | ±25 | mA |
| Ι _Ο | DC Output Sink Current | | ±25 | mA |
| I _{CC} | DC Supply Current per Supply Pin | | ±50 | mA |
| I _{GND} | DC Ground Current per Ground Pin | | ±50 | mA |
| T _{STG} | Storage Temperature Range | | -65 to +150 | °C |
| ΤL | Lead Temperature, 1 mm from Case for | or 10 Seconds | 260 | °C |
| ТJ | Junction Temperature under Bias | | +150 | °C |
| θ_{JA} | Thermal Resistance | SOIC TSSOP | 125 170 | °C/W |
| PD | Power Dissipation in Still Air at 85°C | SOIC TSSOP | 500 450 | mW |
| MSL | Moisture Sensitivity | | Level 1 | |
| F_{R} | Flammability Rating | Oxygen Index: 30% – 35% | UL 94 V–0 @ 0.125 in | |
| V _{ESD} | ESD Withstand Voltage | Human Body Model (Note 1) Machine Model (Note 2) Charged Device Model (Note 3) | > 4000 > 300 > 1000 | V |
| I _{Latchup} | Latchup Performance | Above V_{CC} and Below GND at 85°C (Note 4) | ±300 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected. 1. Tested to EIA/JESD22–A114–A.

2. Tested to EIA/JESD22-A115-A.

3. Tested to JESD22-C101-A.

4. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Parameter | | Min | Max | Unit |
|---------------------------------|--|---------|-----|-----------------|------|
| V _{CC} | DC Supply Voltage (Referenced | to GND) | 4.5 | 5.5 | V |
| V _I , V _O | DC Input Voltage, Output Voltage (Referenced | to GND) | 0 | V _{CC} | V |
| T _A | Operating Temperature, All Package Types | | -55 | +125 | °C |
| t _r , t _f | Input Rise and Fall Time (Figure 1) | | - | (Note 5) | ns |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability. 5. No Limit when $V_I \approx 50\% V_{CC}$, $I_{CC} > 1 \text{ mA}$.

6. Unused inputs may not be left open. All inputs must be tied to a high-logic voltage level or a low-logic input voltage level.

| | | | | Temperature Limit | | | | | | |
|---------------------|--|---|-----------------|-------------------|------------|------------|------------|------------|------------|------|
| | | | V _{cc} | −55°C | to 25°C | ≤8 | 5°C | ≤12 | 25°C | 1 |
| Symbol | Parameter | Test Conditions | Volts | Min | Max | Min | Max | Min | Max | Unit |
| V _{T+} max | Maximum Positive–Going Input Threshold Voltage | $\begin{array}{l} V_{O} = 0.1 \ V \ or \ V_{CC} - 0.1 \ V \\ I_{out} \leq 20 \ \mu A \end{array} \end{array} \label{eq:VC}$ | 4.5 5.5 | | 1.9 2.1 | | 1.9 2.1 | | 1.9 2.1 | V |
| V_{T+} min | Minimum Positive–Going Input Threshold Voltage | $\begin{array}{l} V_{O}=0.1 \ V \ or \ V_{CC}-0.1 \ V \\ I_{out} \leq 20 \ \mu A \end{array} \end{array} \label{eq:VC}$ | 4.5 5.5 | 1.2 1.4 | | 1.2 1.4 | | 1.2 1.4 | | V |
| V _{T-} max | Maximum Negative–Going Input Threshold Voltage | $\begin{array}{l} V_{O}=0.1 \ V \ or \ V_{CC}-0.1 \ V \\ I_{out} \leq 20 \ \mu A \end{array} \end{array} \label{eq:VC}$ | 4.5 5.5 | | 1.2 1.4 | | 1.2 1.4 | | 1.2 1.4 | |
| $V_{T-}min$ | Minimum Negative–Going Input Threshold Voltage | $\begin{array}{l} V_{O}=0.1 \ V \ or \ V_{CC}-0.1 \ V \\ I_{out} \leq 20 \ \mu A \end{array} \end{array} \label{eq:VC}$ | 4.5 5.5 | 0.5 0.6 | | 0.5 0.6 | | 0.5 0.6 | | |
| V _H max | Maximum Hysteresis Voltage | $\begin{array}{l} V_{O}=0.1 \ V \ or \ V_{CC}-0.1 \ V \\ I_{out} \leq 20 \ \mu A \end{array} \end{array} \label{eq:VC}$ | 4.5 5.5 | | 1.4 1.5 | | 1.4 1.5 | | 1.4 1.5 | |
| V _H min | Minimum Hysteresis Voltage | $\begin{array}{l} V_{O}=0.1 \ V \ or \ V_{CC}-0.1 \ V \\ I_{out} \leq 20 \ \mu A \end{array} \end{array} \label{eq:VC}$ | 4.5 5.5 | 0.4 0.4 | | 0.4 0.4 | | 0.4 0 4 | | |
| V _{OH} | Minimum High–Level Output Voltage | V _I < V _T _ min I _{out} ≤ 20 μA | 4.5 5.5 | 4.4 5.4 | | 4.4 5.4 | | 4.4 5.4 | | V |
| | | $V_{I} < V_{T-}$ min $ I_{out} \le 4.0$ mA | 4.5 | 3.98 | | 3.84 | | 3.7 | | |
| V _{OL} | Maximum Low–Level Output Voltage | $V_{I} \ge V_{T+} \max_{ I_{out} \le 20 \ \mu A}$ | 4.5 5.5 | | 0.1 0.1 | | 0.1 0.1 | | 0.1 0.1 | V |
| | | $V_{I} \ge V_{T+} max$ $ I_{out} \le 4.0 mA$ | 4.5 | | 0.26 | | 0.33 | | 0.4 | |
| Ι _{ΙΚ} | Maximum Input Leakage Current | $V_{I} = V_{CC}$ or GND | 5.5 | | ±0.1 | | ±1.0 | | ±1.0 | μA |
| I _{CC} | Maximum Quiescent Supply Current (per package) | $V_I = V_{CC}$ or GND $I_{out} = 0 \ \mu A$ | 5.5 | | 1.0 | | 10 | | 40 | μΑ |
| | | | | ≥ − 55°C 25°C | | C to 12 | 5°C | | | |
| ΔI_{CC} | Additional Quiescent Supply Current | $V_I = 2.4 V$, Any One Input $V_I = V_{CC}$ or GND, Other Inputs $I_{out} = 0 \mu A$ | 5.5 | | 2.9 | | | 2.4 | | mA |

DC ELECTRICAL CHARACTERISTICS (Voltages Referenced to GND)

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC CHARACTERISTICS ($C_L = 50 \text{ pF}$; Input $t_r = t_f = 6.0 \text{ ns}$)

| | | | | Guaranteed Limit | | | | | | |
|--|---|---|---------|---|---------|-----|-----|-----|------|------|
| | | | | −55°C | to 25°C | ≤8 | 5°C | ≤12 | 25°C | |
| Symbol | Parameter | Test Conditions | Figures | Min | Max | Min | Max | Min | Мах | Unit |
| | | | | | | | | | | |
| t _{PLH} , t _{PHL} | Maximum Propagation Delay, Input A to Output Y (L to H) | $V_{CC} = 5.0 \text{ V} \pm 10\%$ $C_L = 50 \text{ pF}$, Input $t_r = t_f = 6.0 \text{ ns}$ | 1 & 2 | | 32 | | 40 | | 48 | ns |
| t _{TLH} , t _{THL} | Maximum Output Transition Time, Any Output | $V_{CC} = 5.0 \text{ V} \pm 10\%$ $C_L = 50 \text{ pF}$, Input $t_r = t_f = 6.0 \text{ ns}$ | 1&2 | | 15 | | 19 | | 22 | ns |
| | | • | · | Typical @ 25°C, V _{CC} = 5.0 V | | | • | | | |

| | | Typical @ 25°C, V _{CC} = 5.0 V | | ĺ |
|-----------------|---|---|----|---|
| C _{PD} | Power Dissipation Capacitance, per Inverter (Note 7) | 32 | pF | |
| | determine the net lead dynamic network constructions $\mathbf{D} = \mathbf{C} + \frac{1}{2} \mathbf{C}$ | | | |

7. Used to determine the no–load dynamic power consumption: $P_D = C_{PD} V_{CC}^2 f + I_{CC} V_{CC}$.

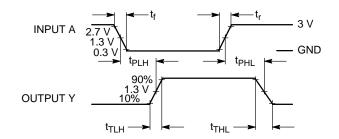
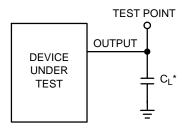


Figure 1. Switching Waveforms



*Includes all probe and jig capacitance.

Figure 2. Test Circuit

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-------------------|------------|-----------------------|
| MC74HCT14ADG | SOIC-14 NB | 55 Units / Rail |
| NLV74HCT14ADG* | (Pb-Free) | 55 Units / Rail |
| MC74HCT14ADR2G | SOIC-14 NB | 2500 / Tana & Real |
| NLV74HCT14ADR2G* | (Pb–Free) | 2500 / Tape & Reel |
| MC74HCT14ADTR2G | TSSOP-14 | 2500 / Tape & Reel |
| NLV74HCT14ADTR2G* | (Pb-Free) | |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

*NLV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q100 Qualified and PPAP Capable.





*For additional information on our Pb–Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

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|---|---|---|--|
| STYLE 5: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. NO CONNECTION 7. COMMON ANODE 8. COMMON CATHODE 10. ANODE/CATHODE 11. ANODE/CATHODE 12. ANODE/CATHODE 13. NO CONNECTION 14. COMMON ANODE | STYLE 6: PIN 1. CATHODE 2. CATHODE 3. CATHODE 4. CATHODE 5. CATHODE 6. CATHODE 7. CATHODE 8. ANODE 9. ANODE 10. ANODE 11. ANODE 12. ANODE 13. ANODE 14. ANODE | STYLE 7: PIN 1. ANODE/CATHODE 2. COMMON ANODE 3. COMMON CATHODE 4. ANODE/CATHODE 5. ANODE/CATHODE 6. ANODE/CATHODE 8. ANODE/CATHODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. COMMON CATHODE 12. COMMON ANODE 13. ANODE/CATHODE 14. ANODE/CATHODE | STYLE 8: PIN 1. COMMON CATHODE 2. ANODE/CATHODE 3. ANODE/CATHODE 4. NO CONNECTION 5. ANODE/CATHODE 6. ANODE/CATHODE 7. COMMON ANODE 9. ANODE/CATHODE 10. ANODE/CATHODE 11. NO CONNECTION 12. ANODE/CATHODE 13. ANODE/CATHODE 14. COMMON CATHODE |

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